## Abstract Submitted for the MAR14 Meeting of The American Physical Society

NMR study of the AF-SC-SC-AF phased transition in a pnictide superconductor LaFeAsO<sub>1-x</sub>H<sub>x</sub><sup>1</sup> NAOKI FUJIWARA, RYOSUKE SAKURAI, Graduate School of Human & Environmental Studies, Kyoto University, Japan, SOUSHI IIMURA, SATORU MATSUISHI, HIDEO HOSONO, Material and Structures Laboratory (MSL), Tokyo Institute of Technology, Japan, YOUICHI YA-MAKAWA, HIROSHI KONTANI, Department of Physics, Nagoya University, Japan — We have performed  $^{75}$ As and  $^{1}$ H NMR measurements in LaFeAsO<sub>1x</sub>H<sub>x</sub>, an isomorphic compound of LaFeAsO<sub>1x</sub>F<sub>x</sub>. LaFeAsO<sub>1x</sub>H<sub>x</sub> is an electron doped system, and O2- can be replaced with H<sup>-</sup> up to x = 0.5. LaFeAsO<sub>1x</sub>H<sub>x</sub> is known for having double superconducting (SC) domes on H doping. Recently, we discovered that a new antiferromagnetic (AF) phase follows the double SC domes on further H doping, forming a symmetric AF-SC-SC-AF phase alignment in the electronic phase diagram [1] Unlike the AF ordering in the lightly H-doped regime, the AF ordering in the highly H-doped regime is attributed to the nesting between electron pockets. In the conference, we will show the data of both NMR spectra and the relaxation rate  $1/T_1$  in the whole doping region. We will discuss the difference of electronic states between the lightly H-doped AF-SC phases and highly H-doped SC-AF phases.

- [1] N. Fujiwara, et al., PRL **111** 097002 (2013)
- [2] Y. Yamakawa, et al., PRB 88 041106 (R) (2013)

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